Supporting Information

# Bulk-heterojunction pushes photoresponse of perovskite solar

# cells to 970 nm

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### Synthesis and characterization

PDPP3T was synthesized using reported method.<sup>[1]</sup> Absorption spectra of films were recorded on a Shimadzu UV-1800 spectrophotometer. The thicknesses of films were measured using a Tencor D-120 profilometer.

### Solar cell fabrication and characterization

Patterned ITO glass with a sheet resistance of 15  $\Omega$  sq<sup>-1</sup> was cleaned by ultrasonics in detergent, deionized water, acetone, isopropanol sequentially and then treated with UV-ozone for 10 min. A 30 nm thick PEDOT layer was formed on ITO glass by spin coating an aqueous dispersion (PEDOT:PSS, Clevios<sup>TM</sup> P VP AI 4083) onto ITO glass (4000 rpm for 30 s). PEDOT substrates were dried at 150 °C for 10 min, and then transferred into a N<sub>2</sub> glovebox. For BHJ cells, a PDPP3T:PC<sub>61</sub>BM blend solution (10~24 mg/mL in chlorobenzene with 4 vol% DIO) was spin coated onto PEDOT at 1200 rpm for 60s. For perovskite cells, the precursor solution (10~19 wt%) was spin coated onto PEDOT at 3000 rpm for 60 s and heated at 100 °C for 30 s. Then PC<sub>61</sub>BM solution (20 mg/mL in chlorobenzene) was spin coated onto CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>

layer at 1500 rpm for 30 s. For the integrated solar cells, a PDPP3T:PC<sub>61</sub>BM blend solution (10~24 mg/mL in chlorobenzene with 4 vol% DIO) was spin coated onto CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> layer at 1200 rpm for 60s. Finally Ca (10 nm) and Al (100 nm) was deposited onto PC<sub>61</sub>BM layer or the blend layer through a shadow mask in vacuo (10<sup>-4</sup> Pa). The effective area for the cells is 4 mm<sup>2</sup>. *J-V* curves were measured using a computerized Keithley 2420 SourceMeter. Device characterization was performed in air using a solar simulator (Newport 91159A, AM 1.5G, 100 mW/cm<sup>2</sup>). The illumination intensity was determined using a monocrystalline silicon cell (Oriel 91150, 2×2 cm) calibrated by NREL. EQE spectra were measured using a QE-R3011 system (Enli Technology).



Fig. S1 The energy level diagram for the integrated cells.<sup>[2,3]</sup>



**Fig. S2** *J-V* curves (a) and EQE spectra (b) for BHJ cells, perovskite cells and the integrated cells. The thicknesses for  $CH_3NH_3PbI_3$  layer and PDPP3T:PC<sub>61</sub>BM (1:2) layer are 70 nm and 130 nm, respectively.

Table S1 Performance data for BHJ cells, perovskite cells and the integrated cells.

Cell type	V <sub>oc</sub>	$J_{ m sc}$	Cal. $J_{\rm sc}$	FF	PCE
	[V]	[mA/cm <sup>2</sup> ]	[mA/cm <sup>2</sup> ]	[%]	[%]
BHJ cell	0.67	8.82	8.76	67.07	3.96
Perovskite cell	0.82	7.49	7.42	74.08	4.55
Integrated cell	0.79	10.86	10.89	59.26	5.08



**Fig. S3** *J-V* curves (a) and EQE spectra (b) for the integrated solar cells with different PDPP3T:PC<sub>61</sub>BM ratio.

Table S2 Performance data for the integrated solar cells<sup>a</sup> with different D/A ratio.

PDPP3T:PC <sub>61</sub> B	$V_{\rm oc}$	$J_{ m sc}$	Cal. $J_{\rm sc}$	FF	PCE
М	[V]	[mA/cm <sup>2</sup> ]	[mA/cm <sup>2</sup> ]	[%]	[%]
0:1 <sup>b</sup>	0.90	13.09	12.78	80.33	9.46
1:2°	0.86	12.67	12.55	60.84	6.63
1:4°	0.87	13.12	12.91	69.37	7.92
1:6°	0.88	12.78	12.62	73.72	8.29

<sup>a</sup> thickness for perovskite layer: 150 nm

 $^{\rm b}$  thickness for  $PC_{61}BM$  layer: 80 nm

<sup>c</sup> thickness for blend layer: 130 nm



**Fig. S4** (a) J-V curves for a perovskite solar cell (ITO/PEDOT/150nm CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>/80nm PC<sub>61</sub>BM/Ca/Al) under forward (from short circuit to open circuit) and reverse (from open circuit to short circuit) scans with bias step of 0.013 V and scan rate of 0.13 V s<sup>-1</sup>. (b) J-V curves for an integrated solar cell (ITO/PEDOT/150nm CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>/80nm PDPP3T:PC<sub>61</sub>BM (1:4)/Ca/Al) under the same measurement conditions.

### References

- [1] K. H. Hendriks, G. H. L. Heintges, V. S. Gevaerts, M. M. Wienk and R. A. J. Janssen, *Angew. Chem. Int. Ed.*, 2013, **52**, 8341.
- [2] P. Docampo, J. M. Ball, M. Darwich, G. E. Eperon and H. J. Snaith, *Nat. Commun.*, 2013, 4, 2761.
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